

## DC-6GHz 6-BIT DIGITAL ATTENUATOR

GaAs Monolithic Microwave IC in SMD leadless package

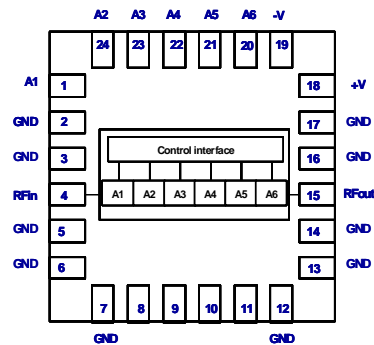
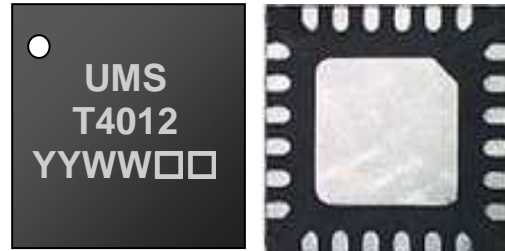
### Description

The CHT4012-QDG is a DC-6GHz monolithic 6-bit digital attenuator with a LSB = 0.5dB offering a high dynamic range and a high accuracy, the RMS amplitude error is typically as low as 0.3dB. The circuit provides low insertion loss 2.5dB associated to input and output return losses better than 13dB. A CMOS and TTL compatible interface is available on chip.

It is designed for a wide range of applications, from military to commercial communication systems.

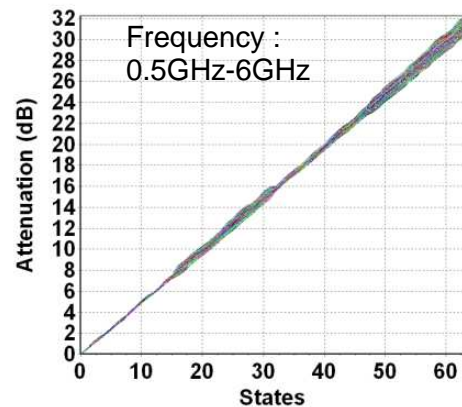
The circuit is manufactured with a pHEMT process, 0.25µm gate length, via holes through the substrate, air bridges and electron beam gate lithography.

It is supplied in RoHS compliant SMD package.



### Main Features

- Broadband performances: DC-6GHz
- Insertion Loss (state 0): 2.5dB
- RMS attenuation error: 0.3dB
- RMS phase variation: 1deg
- DC bias: V+=5V and V-=-5V
- No decoupling capacitance on Input and Output RF accesses
- 24L-QFN4x4
- MSL1



### Main Characteristics

Tamb.= +25°C

Symbol	Parameter	Min	Typ	Max	Unit
Freq	Frequency range	DC		6	GHz
IL	Insertion Loss		2.5		dB
Rms_att_err	RMS of attenuation error		0.3		dB
Rms_phivar	RMS of phase variation (0.5 to 6GHz)		1		°

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## Main Characteristics

Tamb.= +25°C

Symbol	Parameter	Min	Typ	Max	Unit
Freq	Frequency range	DC		6	GHz
IL	Insertion Loss		2.5		dB
S11	Input Return Loss		-15		dB
S22	Output Return Loss		-15		dB
P1dB	Input power at 1dB gain compression		20		dBm
Dyn	Dynamic		31.5		dB
LSB	Attenuator elementary step		0.5		dB
Att_err	Attenuation error		-0.7/0.4		dB
Rms_att_err	RMS attenuation error		0.3		dB
Phivar	Phase variation (0.5 to 6GHz)		-3/+2		°
Rms_phivar	RMS phase variation (0.5 to 6GHz)		1		°
Sw_t	Switching time		15		ns
V+	Positive supply voltage		5		V
V-	Negative supply voltage		-5		V
Vctrl_L	Control voltage low level		0	0.4	V
Vctrl_H	Control voltage high level	2.4		7	V
I_V+	Positive supply DC current		5		mA
I_V-	Negative supply DC current		5		mA

These values are representative of onboard measurements as defined on the drawing in paragraph "Evaluation mother board".

## Definitions

n: Attenuator state index with  $0 \leq n \leq 63$

Phase\_S21(n) : Measured phase of S21 in degree at attenuation state n

dB\_S21(n) : Measured magnitude of S21 in dB at attenuation state n

### Attenuation Error (Att\_err)

$$\text{Att\_err}(n) = \text{dB\_S21}(n) - \text{dB\_S21}(0) - 0.5 \cdot n \text{ (dB)}$$

The translation of Att\_err(n) from dB to linear is given by:  $\text{Att\_err\_lin}(n) = 10^{\frac{\text{Att\_err}(n)}{20}}$

### Phase variation (Phivar)

$$\text{Phivar}(n) = \text{Phase\_S21}(n) - \text{Phase\_S21}(0) \text{ (}^\circ\text{)}$$

### RMS Attenuation Error (Rms\_att\_err)

$$\text{Rms\_att\_err} = 20 \log \left( 1 + \sqrt{\frac{1}{64} \cdot \sum_{n=0}^{63} (1 - \text{Att\_err\_lin}(n))^2} \right) \text{ (dB)}$$

### RMS Phase variation (Rms\_Phivar)

$$\text{Rms\_Phivar} = \sqrt{\frac{\sum_{n=0}^{63} (\text{Phivar}(n))^2}{64}} \text{ (}^\circ\text{)}$$

## Absolute Maximum Ratings

Tamb.= +25°C <sup>(1)</sup>

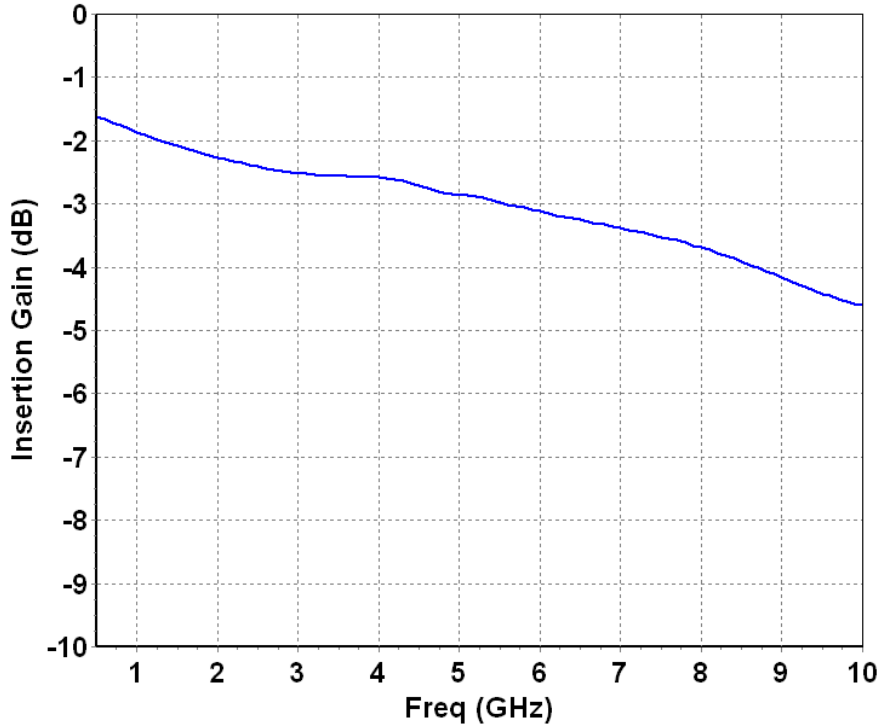
Symbol	Parameter	Values	Unit
V+	Maximum positive voltage	8V	V
V-	Minimum negative voltage	-8	V
Ai	CTRL voltage (Vctrl_low, Vctrl_high)	-2 to 8	V
Pin	Maximum Input power	23	dBm
Tj	Junction temperature	175	°C
Ta	Operating temperature range	-40 to +85	°C
Tstg	Storage temperature range	-55 to +150	°C

<sup>(1)</sup> Operation of this device above anyone of these parameters may cause permanent damage.

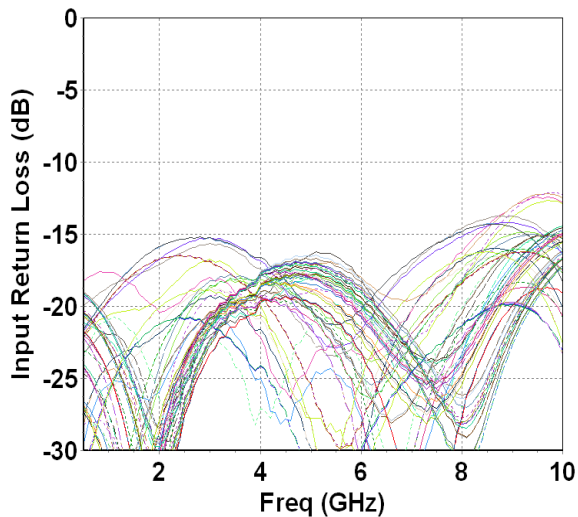
## Typical Board Measurements

Tamb. = +25°C, V+ = +5V, V- = -5V

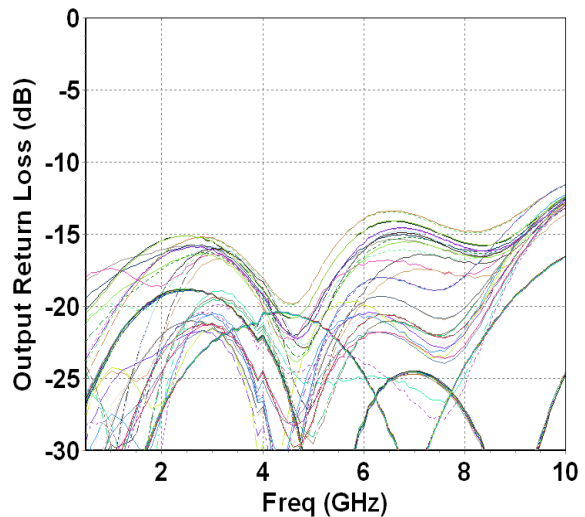
### Insertion Loss (Attenuator state 0)



### Input Return Loss All States



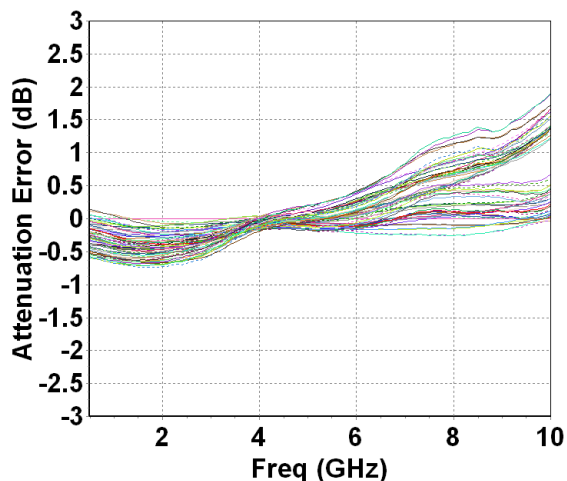
### Output Return Loss All States



**Typical Board Measurements**

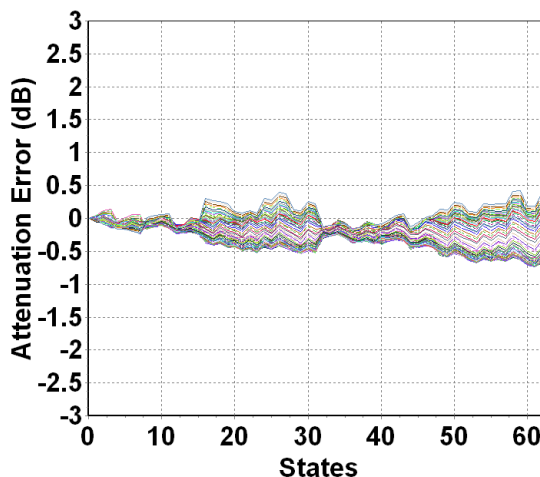
Tamb.= +25°C, V+ = +5V, V- = -5V

**Attenuation Error versus Frequency**

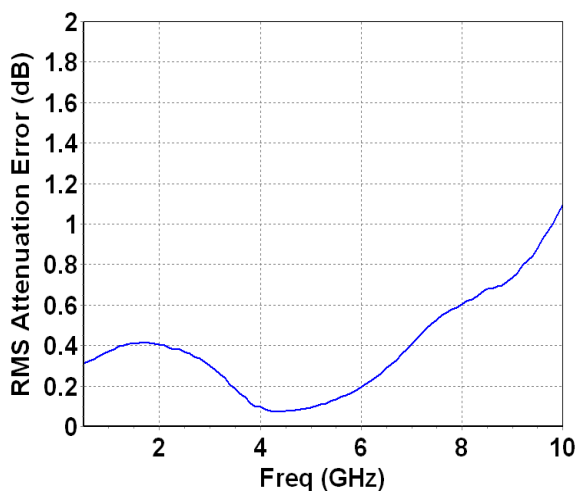


**Attenuation Error versus States**

0.5GHz < Frequency < 6Ghz

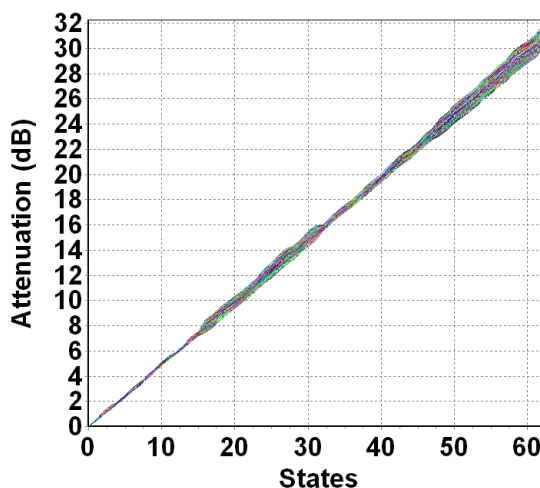


**RMS Attenuation Error versus Frequency**



**Attenuation versus States**

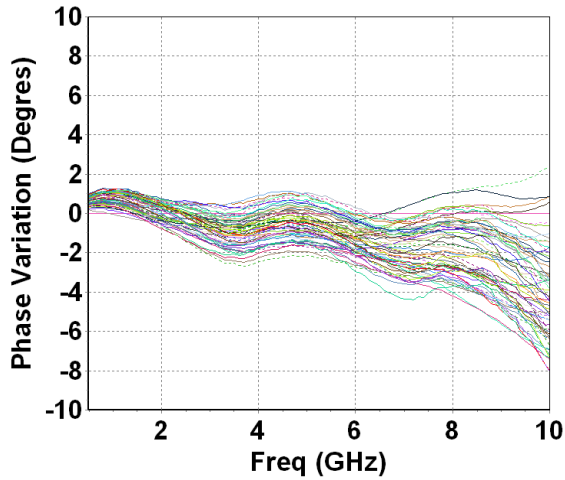
0.5GHz < Frequency < 6Ghz



## Typical Board Measurements

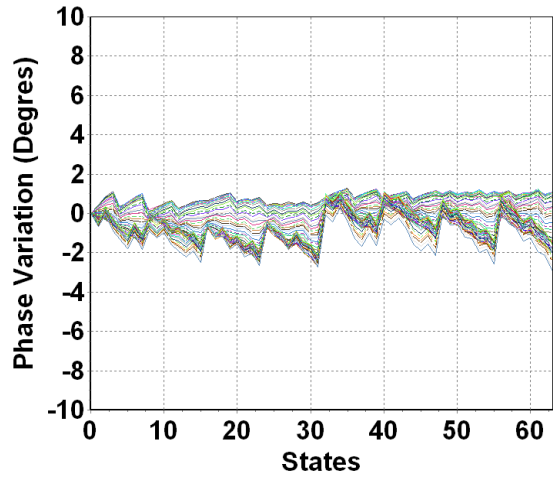
Tamb.= +25°C, V+ = +5V, V- = -5V

### Phase Variation versus Frequency

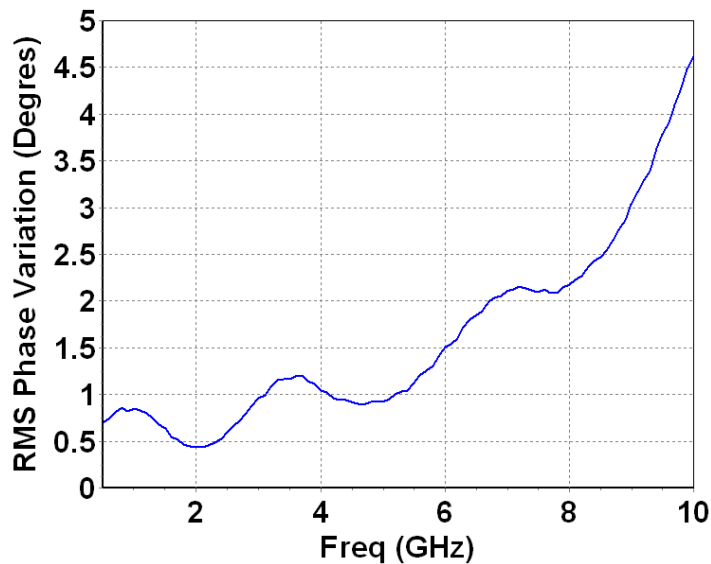


### Phase Variation versus States

0.5GHz < Frequency < 6GHz



### RMS of Phase Variation versus Frequency



**Typical Board Measurements**

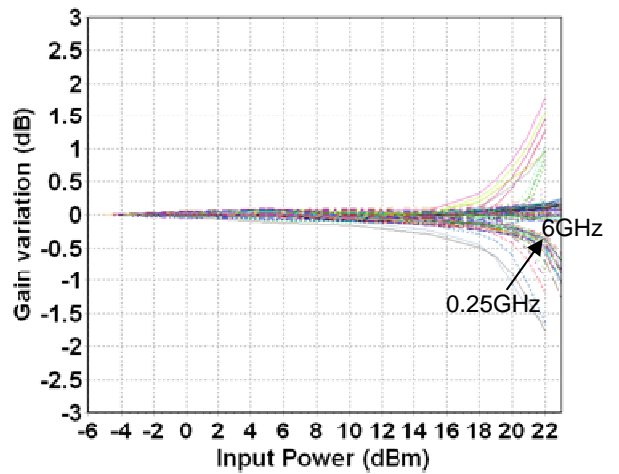
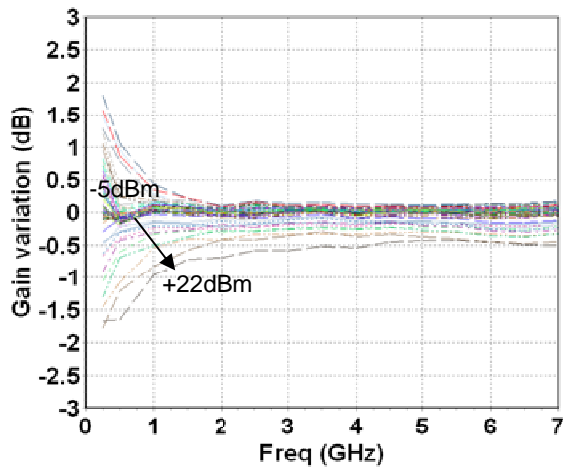
Tamb.= +25°C, V+ = +5V, V- = -5V

**Variation of the Gain versus Frequency**

Attenuator states : 0 / 1 / 2 / 4 / 8 / 16 / 32 / 63  
 Input power : -5 to 22dBm

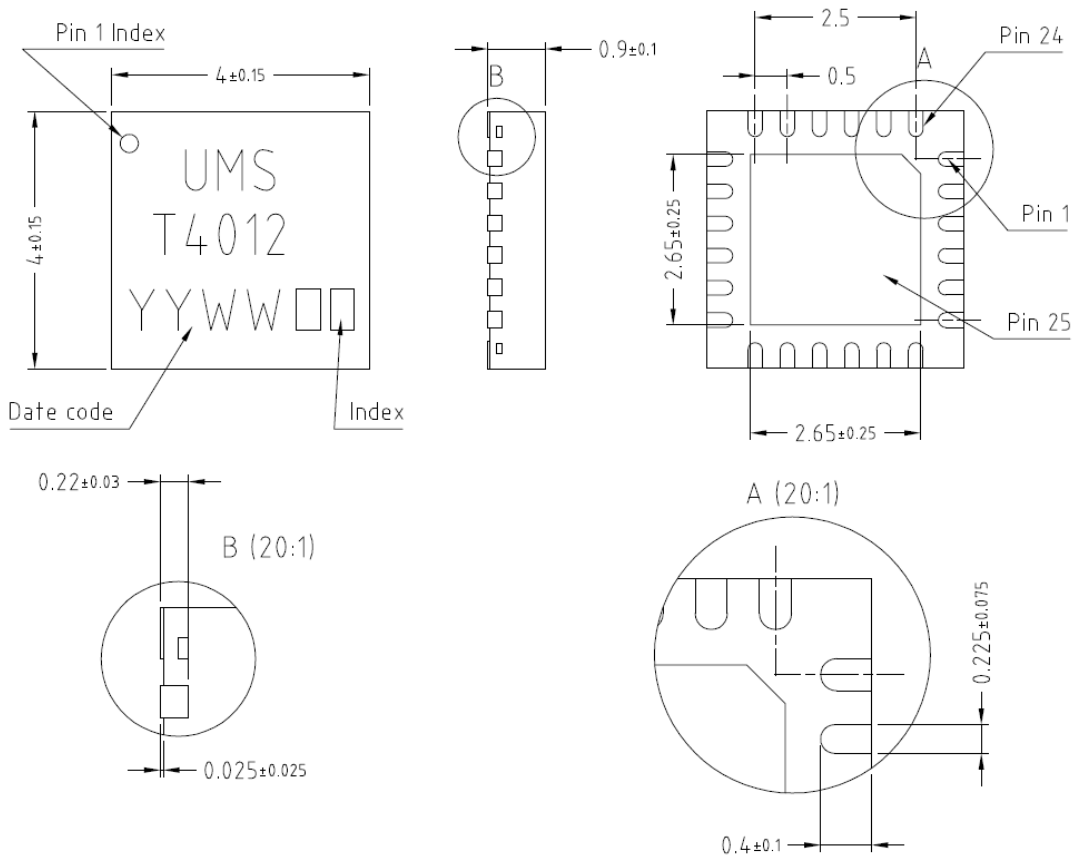
**Variation of the Gain versus Input Power**

Attenuator states : 0 / 1 / 2 / 4 / 8 / 16 / 32 / 63  
 Frequency : 0.25GHz to 6GHz



# CHT4012-QDG DC-6GHz 6-BIT DIGITAL ATTENUATOR

## Package outline <sup>(1)</sup>



Matt tin, Lead Free	(Green)	1- A1	9- Nc	17- Gnd <sup>(2)</sup>
Units :	mm	2- Gnd <sup>(2)</sup>	10- Nc	18- V+
From the standard :	JEDEC MO-220	3- Gnd <sup>(2)</sup>	11- Nc	19- V-
	(VGGD)	4- RF in	12- Gnd <sup>(2)</sup>	20- A6
	25- GND	5- Gnd <sup>(2)</sup>	13- Gnd <sup>(2)</sup>	21- A5
		6- Gnd <sup>(2)</sup>	14- Gnd <sup>(2)</sup>	22- A4
		7- Gnd <sup>(2)</sup>	15- RF out	23- A3
		8- Nc	16- Gnd <sup>(2)</sup>	24- A2

<sup>(1)</sup> The package outline drawing included to this data-sheet is given for indication. Refer to the application note AN0017 (<http://www.ums-gaas.com>) for exact package dimensions.

<sup>(2)</sup> It is strongly recommended to ground all pins marked "Gnd" through the PCB board. Ensure that the PCB board is designed to provide the best possible ground to the package.



## Biassing recommendations

Pin number	Pad name	Value
1	A1	0V / 3.3V or 0V / 5V
24	A2	0V / 3.3V or 0V / 5V
23	A3	0V / 3.3V or 0V / 5V
22	A4	0V / 3.3V or 0V / 5V
21	A5	0V / 3.3V or 0V / 5V
20	A6	0V / 3.3V or 0V / 5V
19	V-	-5V
18	V+	+5V

### NOTE:

Control voltages of the attenuator bits are both CMOS and TTL compatible

# CHT4012-QDG DC-6GHz 6-BIT DIGITAL ATTENUATOR

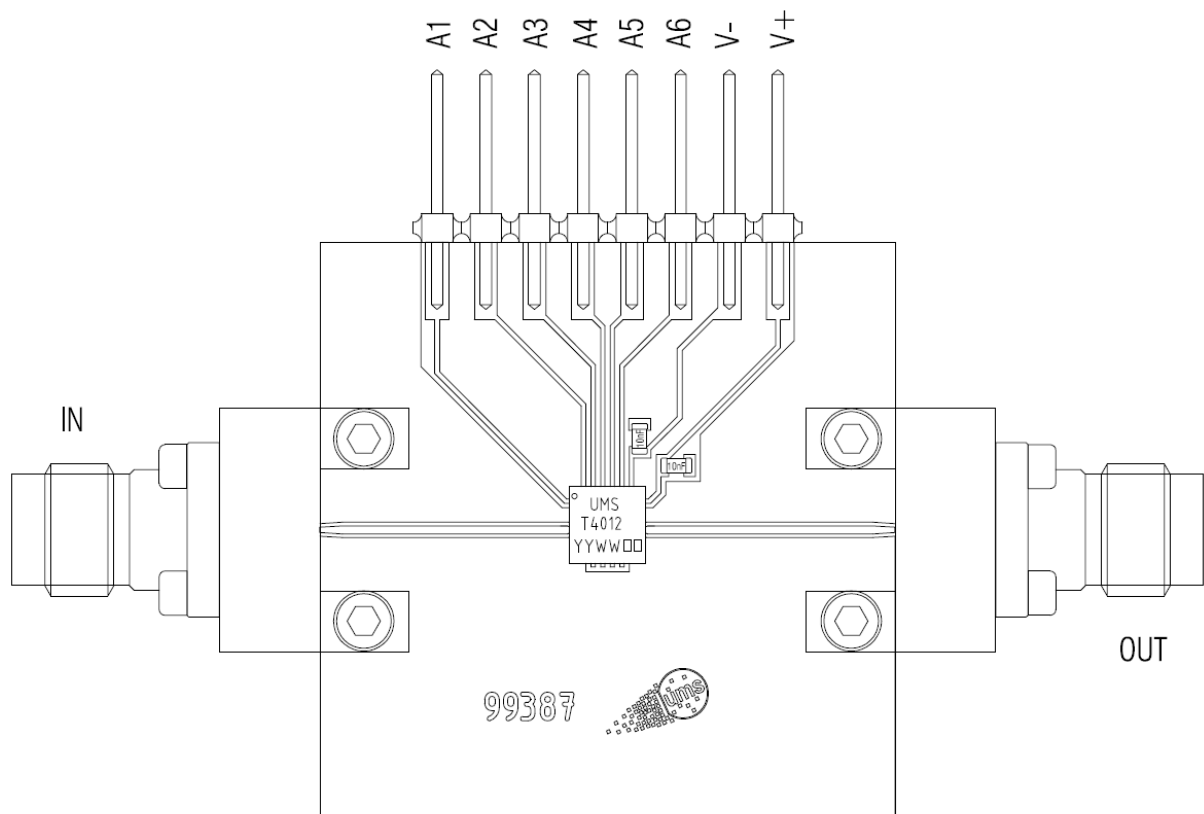
## Attenuator control table

Voltage to apply on the pads A1 to A6:

state	Att (dB)	A6	A5	A4	A3	A2	A1	state	Att (dB)	A6	A5	A4	A3	A2	A1
0	0	0	0	0	0	0	0	33	16.5	3.3	0	0	0	0	3.3
1	0.5	0	0	0	0	0	3.3	34	17	3.3	0	0	0	3.3	0
2	1	0	0	0	0	3.3	0	35	17.5	3.3	0	0	0	3.3	3.3
3	1.5	0	0	0	0	3.3	3.3	36	18	3.3	0	0	3.3	0	0
4	2	0	0	0	3.3	0	0	37	18.5	3.3	0	0	3.3	0	3.3
5	2.5	0	0	0	3.3	0	3.3	38	19	3.3	0	0	3.3	3.3	0
6	3	0	0	0	3.3	3.3	0	39	19.5	3.3	0	0	3.3	3.3	3.3
7	3.5	0	0	0	3.3	3.3	3.3	40	20	3.3	0	3.3	0	0	0
8	4	0	0	3.3	0	0	0	41	20.5	3.3	0	3.3	0	0	3.3
9	4.5	0	0	3.3	0	0	3.3	42	21	3.3	0	3.3	0	3.3	0
10	5	0	0	3.3	0	3.3	0	43	21.5	3.3	0	3.3	0	3.3	3.3
11	5.5	0	0	3.3	0	3.3	3.3	44	22	3.3	0	3.3	3.3	0	0
12	6	0	0	3.3	3.3	0	0	45	22.5	3.3	0	3.3	3.3	0	3.3
13	6.5	0	0	3.3	3.3	0	3.3	46	23	3.3	0	3.3	3.3	3.3	0
14	7	0	0	3.3	3.3	3.3	0	47	23.5	3.3	0	3.3	3.3	3.3	3.3
15	7.5	0	0	3.3	3.3	3.3	3.3	48	24	3.3	3.3	0	0	0	0
16	8	0	3.3	0	0	0	0	49	24.5	3.3	3.3	0	0	0	3.3
17	8.5	0	3.3	0	0	0	3.3	50	25	3.3	3.3	0	0	3.3	0
18	9	0	3.3	0	0	3.3	0	51	25.5	3.3	3.3	0	0	3.3	3.3
19	9.5	0	3.3	0	0	3.3	3.3	52	26	3.3	3.3	0	3.3	0	0
20	10	0	3.3	0	3.3	0	0	53	26.5	3.3	3.3	0	3.3	0	3.3
21	10.5	0	3.3	0	3.3	0	3.3	54	27	3.3	3.3	0	3.3	3.3	0
22	11	0	3.3	0	3.3	3.3	0	55	27.5	3.3	3.3	0	3.3	3.3	3.3
23	11.5	0	3.3	0	3.3	3.3	3.3	56	28	3.3	3.3	3.3	0	0	0
24	12	0	3.3	3.3	0	0	0	57	28.5	3.3	3.3	3.3	0	0	3.3
25	12.5	0	3.3	3.3	0	0	3.3	58	29	3.3	3.3	3.3	0	3.3	0
26	13	0	3.3	3.3	0	3.3	0	59	29.5	3.3	3.3	3.3	0	3.3	3.3
27	13.5	0	3.3	3.3	0	3.3	3.3	60	30	3.3	3.3	3.3	3.3	0	0
28	14	0	3.3	3.3	3.3	0	0	61	30.5	3.3	3.3	3.3	3.3	0	3.3
29	14.5	0	3.3	3.3	3.3	0	3.3	62	31	3.3	3.3	3.3	3.3	3.3	0
30	15	0	3.3	3.3	3.3	3.3	0	63	31.5	3.3	3.3	3.3	3.3	3.3	3.3
31	15.5	0	3.3	3.3	3.3	3.3	3.3								
32	16	3.3	0	0	0	0	0								

**Evaluation mother board**

- Compatible with the proposed footprint.
- Based on typically Ro4003 / 8mils or equivalent.
- Using a micro-strip to coplanar transition to access the package.
- Recommended for the implementation of this product on a module board.
- Decoupling capacitors of 10nF  $\pm$ 10% are recommended for indicated DC accesses.
- See application note AN0017 for details.

**Note**

An external capacitance is requested to protect the device from any external DC voltage that might be present on the RF accesses.

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## Recommended package footprint

Refer to the application note AN0017 available at <http://www.ums-gaas.com> for package footprint recommendations.

## SMD mounting procedure

For the mounting process standard techniques involving solder paste and a suitable reflow process can be used. For further details, see application note AN0017.

## Recommended environmental management

Refer to the application note AN0019 available at <http://www.ums-gaas.com> for environmental data on UMS package products.

## Recommended ESD management

Refer to the application note AN0020 available at <http://www.ums-gaas.com> for ESD sensitivity and handling recommendations for the UMS package products.

## Ordering Information

QFN 4x4 RoHS compliant package:                      CHT4012-QDG/XY  
Stick: XY = 20    Tape & reel: XY = 21

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